



BCX41

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125V NPN MEDIUM POWER TRANSISTOR IN SOT23

Features

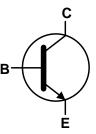
- BV_{CEO} > 125V
- I_C = 800mA High Continuous Collector Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

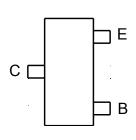
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

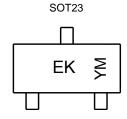
Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
BCX41TA	AEC-Q101	EK	7	8	3000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3.Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, see https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\begin{array}{l} \mathsf{EK} = \mathsf{Product} \; \mathsf{Type} \; \mathsf{Marking} \; \mathsf{Code} \\ \mathsf{YM} = \mathsf{Date} \; \mathsf{Code} \; \mathsf{Marking} \\ \mathsf{Y} \; \mathsf{or} \; \overline{\mathsf{Y}} = \mathsf{Year} \; (\mathsf{ex:} \; \mathsf{E} = 2017) \\ \mathsf{M} \; \mathsf{or} \; \overline{\mathsf{M}} = \mathsf{Month} \; (\mathsf{ex:} \; 9 = \mathsf{September}) \end{array}$

Date Code Key

Date Code Ney												
Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	Н		J	K	L	М	N	0	Р	O
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Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	125	V
Collector-Emitter Voltage	V _{CEO}	125	V
Emitter-Base Voltage	V _{EBO}	5	V
Continuous Collector Current	Ic	800	mA
Peak Pulse Current	I _{CM}	1	А
Base Current	Ι _Β	100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Dower Dissination	(Note 5)	נ	310	mW
Power Dissipation	(Note 6)	P_D	350	IIIVV
Thermal Desistance Junction to Ambient	(Note 5)	5	403	0000
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\Theta JA}$	357	°C/W
Thermal Resistance, Junction to Leads	(Note 7)	R _{ÐJL}	350	°C/W
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

ESD Ratings (Note 8)

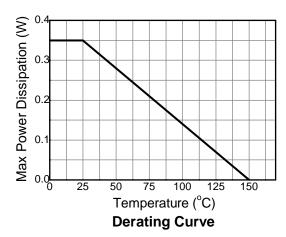
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

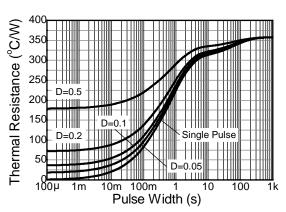
Notes:

- 5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper in still air condition; the device is measured when operating in a steady-state condition.
- 6. Same as note (6), except the device is mounted on 15mm x 15mm FR-4 PCB.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

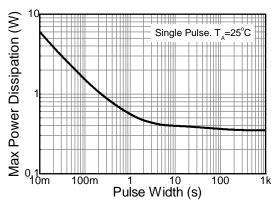


Thermal Characteristics and Derating Information (@TA = +25°C, unless otherwise specified.)





Transient Thermal Impedance



Pulse Power Dissipation



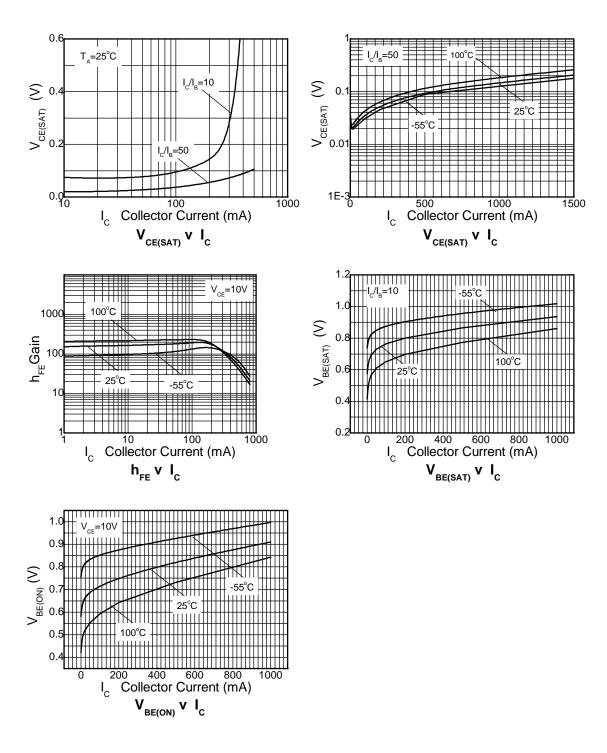
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage	BV _{CES}	125	_	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	125	_	_	V	I _{CEO} = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	_	_	V	$I_{EBO} = 10\mu A$
Collector-Base Cut-Off Current	I _{CES}	_		100 10	nΑ μΑ	V _{CB} = 100V V _{CB} = 100V, T _A = +150°C
Collector Cut-Off Current	I _{CEX}	_	_	10 75	μΑ μΑ	$V_{CE} = 100V, V_{BE} = 0.2V, \ T_{A} = +85^{\circ}C \ V_{CE} = 100V, V_{BE} = 0.2V, \ T_{A} = +125^{\circ}C$
Emitter-base Cut-off Current	I _{EBO}	_	_	100	nA	V _{EB} = 5.6V
ON CHARACTERISTICS (Note 10)						
Static Forward Current Transfer Ratio	h _{FE}	25 63 40	_	_	_	$I_C = 100\mu A, V_{CE} = 1V$ $I_C = 100mA, V_{CE} = 1V$ $I_C = 200mA, V_{CE} = 1V$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	0.9	V	$I_C = 300 \text{mA}, I_B = 30 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	_	1.4	V	$I_C = 300 \text{mA}, I_B = 30 \text{mA}$
SMALL SIGNAL CHARACTERISTICS (Note 9)						_
Transition Frequency	f_T	_	100	_	MHz	$I_C = 10$ mA, $V_{CE} = 5$ V, $f = 20$ MHz
Output Capacitance	C _{OBO}	_	12	_	pF	V _{CB} = 10V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.



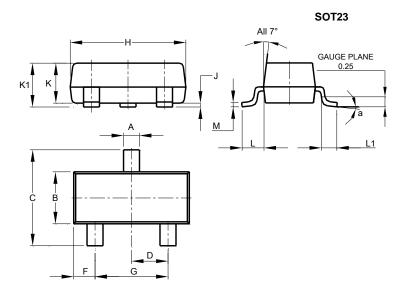
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

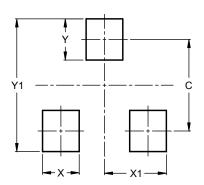
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	0°	8°	_		
All	Dimens	ions in	mm		

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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